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### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Obsolete
Core Processor	RL78
Core Size	16-Bit
Speed	32MHz
Connectivity	CSI, I <sup>2</sup> C, LINbus, UART/USART
Peripherals	DMA, LVD, POR, PWM, WDT
Number of I/O	21
Program Memory Size	128KB (128K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	12K x 8
Voltage - Supply (Vcc/Vdd)	1.6V ~ 5.5V
Data Converters	A/D 8x8/10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	30-LSSOP (0.240", 6.10mm Width)
Supplier Device Package	30-LSSOP
Purchase URL	<a href="https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f101agasp-x0">https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f101agasp-x0</a>

Table 1-1. List of Ordering Part Numbers

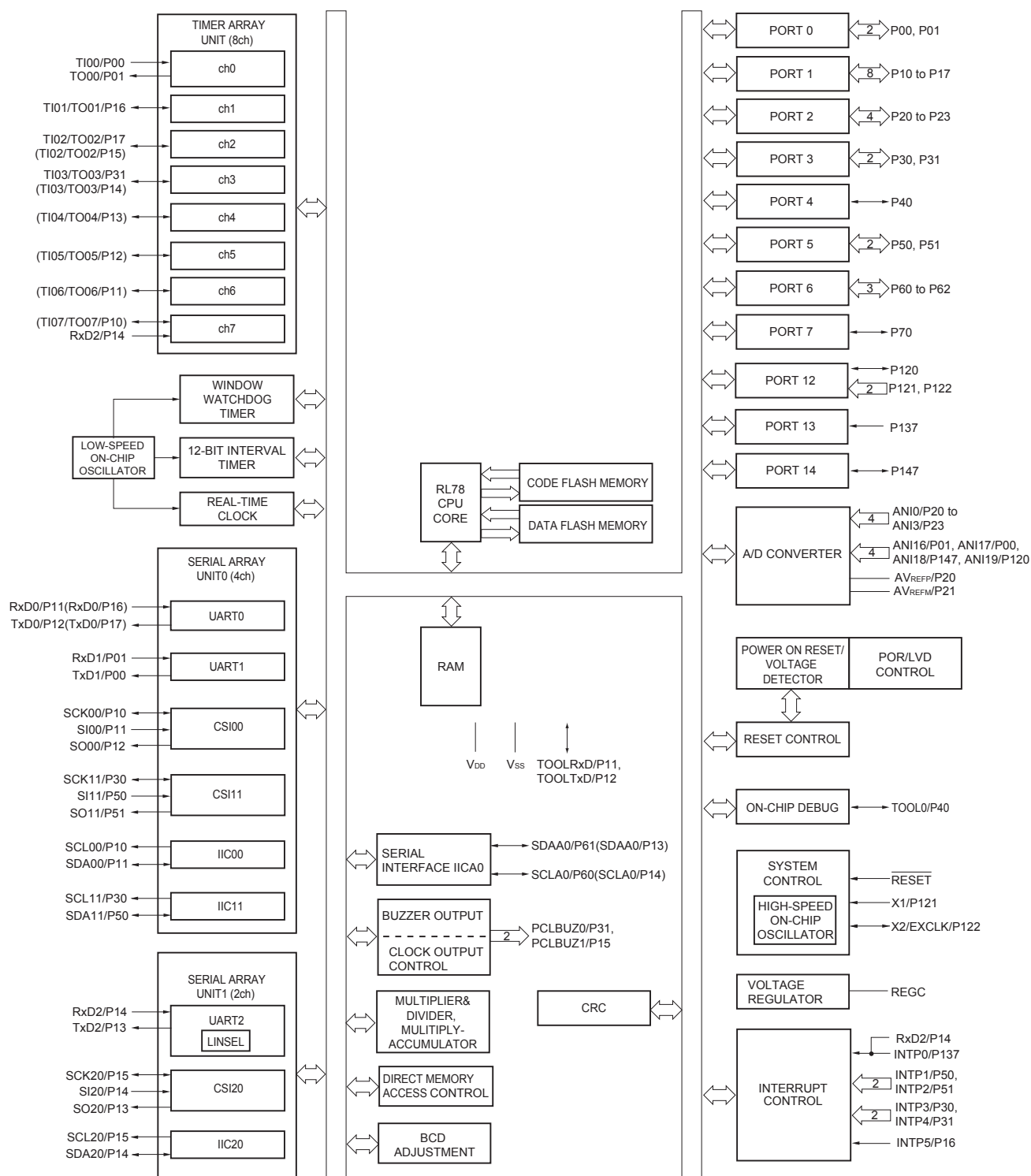
(12/12)

Pin count	Package	Data flash	Fields of Application <sup>Note</sup>	Ordering Part Number
128 pins	128-pin plastic LFQFP (14 × 20 mm, 0.5 mm pitch)	Mounted	A	R5F100SHAFB#V0, R5F100SJAFB#V0, R5F100SKAFB#V0, R5F100SLAFB#V0
			D	R5F100SHAFB#X0, R5F100SJAFB#X0, R5F100SKAFB#X0, R5F100SLAFB#X0
		Not mounted	A	R5F100SHDFB#V0, R5F100SJDFB#V0, R5F100SKDFB#V0, R5F100SLDFB#V0
			D	R5F100SHDFB#X0, R5F100SJDFB#X0, R5F100SKDFB#X0, R5F100SLDFB#X0
128 pins	128-pin plastic LFQFP (14 × 20 mm, 0.5 mm pitch)	Mounted	A	R5F101SHAFB#V0, R5F101SJAFB#V0, R5F101SKAFB#V0, R5F101SLAFB#V0
			D	R5F101SHAFB#X0, R5F101SJAFB#X0, R5F101SKAFB#X0, R5F101SLAFB#X0
		Not mounted	A	R5F101SHDFB#V0, R5F101SJDFB#V0, R5F101SKDFB#V0, R5F101SLDFB#V0
			D	R5F101SHDFB#X0, R5F101SJDFB#X0, R5F101SKDFB#X0, R5F101SLDFB#X0

**Note** For the fields of application, refer to **Figure 1-1 Part Number, Memory Size, and Package of RL78/G13**.

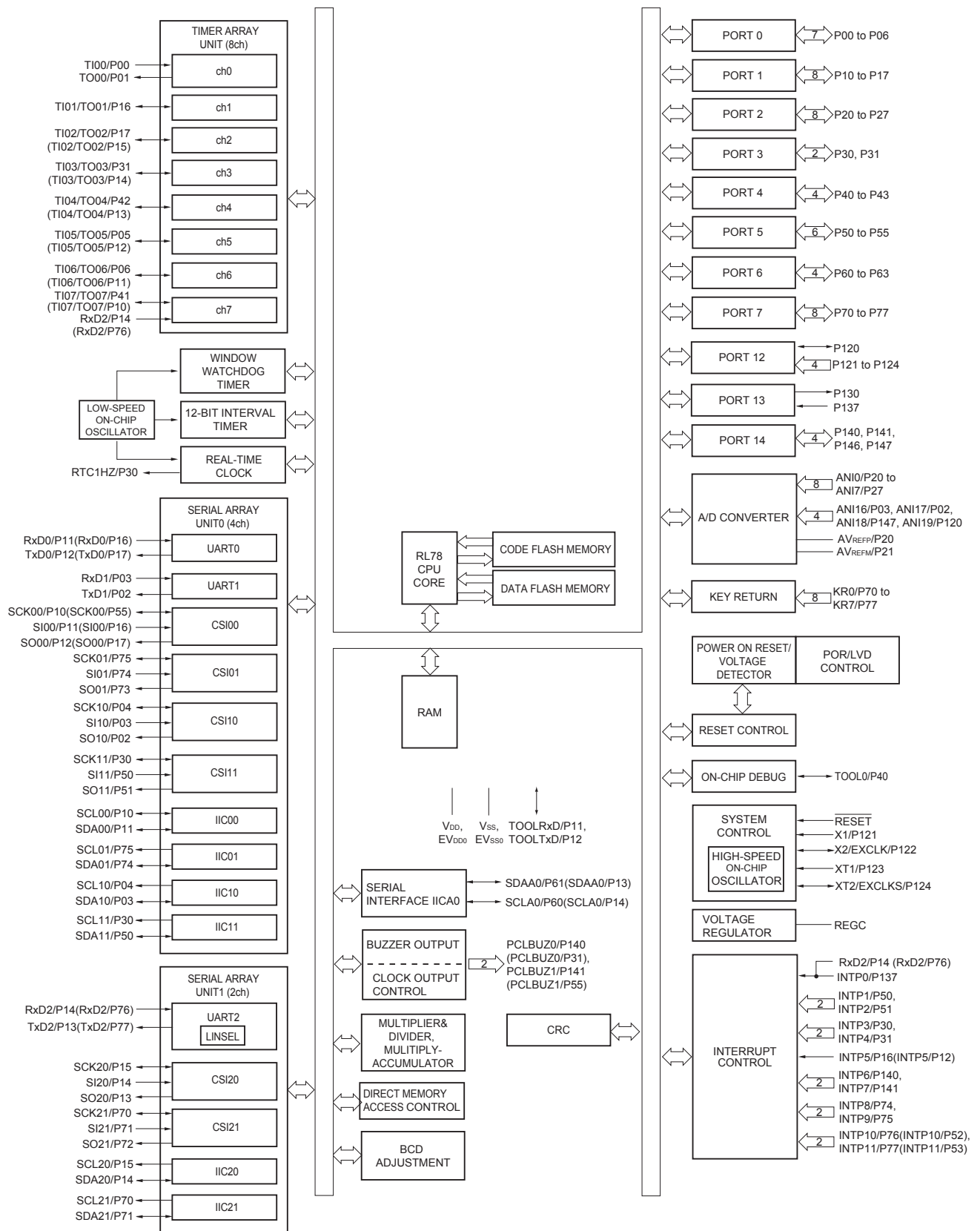
**Caution** The ordering part numbers represent the numbers at the time of publication. For the latest ordering part numbers, refer to the target product page of the Renesas Electronics website.

## 1.5.5 32-pin products



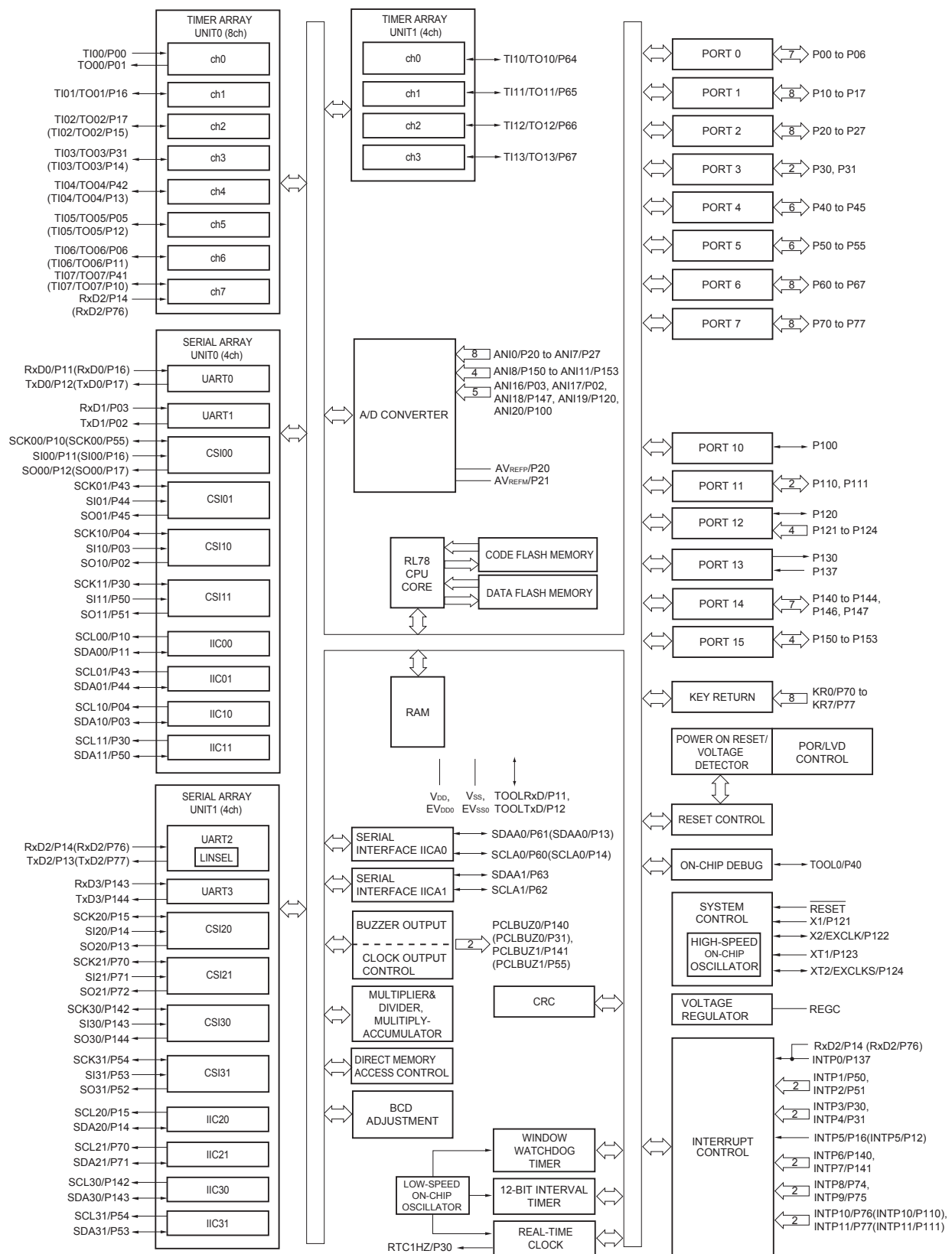
**Remark** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR). Refer to **Figure 4-8 Format of Peripheral I/O Redirection Register (PIOR)** in the RL78/G13 User's Manual.

## 1.5.11 64-pin products



**Remark** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR). Refer to **Figure 4-8 Format of Peripheral I/O Redirection Register (PIOR)** in the RL78/G13 User's Manual.

## 1.5.12 80-pin products



**Remark** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR). Refer to **Figure 4-8 Format of Peripheral I/O Redirection Register (PIOR)** in the RL78/G13 User's Manual.

3. The number of PWM outputs varies depending on the setting of channels in use (the number of masters and slaves) (see **6.9.3 Operation as multiple PWM output function** in the RL78/G13 User's Manual).
4. When setting to PIOR = 1

(2/2)

Item	20-pin		24-pin		25-pin		30-pin		32-pin		36-pin	
	R5F1006x	R5F1016x	R5F1007x	R5F1017x	R5F1008x	R5F1018x	R5F100Ax	R5F101Ax	R5F100Bx	R5F101Bx	R5F100Cx	R5F101Cx
Clock output/buzzer output	—		1		1		2		2		2	
	• 2.44 kHz, 4.88 kHz, 9.76 kHz, 1.25 MHz, 2.5 MHz, 5 MHz, 10 MHz (Main system clock: f <sub>MAIN</sub> = 20 MHz operation)											
8/10-bit resolution A/D converter	6 channels		6 channels		6 channels		8 channels		8 channels		8 channels	
Serial interface	[20-pin, 24-pin, 25-pin products] • CSI: 1 channel/simplified I <sup>2</sup> C: 1 channel/UART: 1 channel • CSI: 1 channel/simplified I <sup>2</sup> C: 1 channel/UART: 1 channel [30-pin, 32-pin products] • CSI: 1 channel/simplified I <sup>2</sup> C: 1 channel/UART: 1 channel • CSI: 1 channel/simplified I <sup>2</sup> C: 1 channel/UART: 1 channel • CSI: 1 channel/simplified I <sup>2</sup> C: 1 channel/UART (UART supporting LIN-bus): 1 channel [36-pin products] • CSI: 1 channel/simplified I <sup>2</sup> C: 1 channel/UART: 1 channel • CSI: 1 channel/simplified I <sup>2</sup> C: 1 channel/UART: 1 channel • CSI: 2 channels/simplified I <sup>2</sup> C: 2 channels/UART (UART supporting LIN-bus): 1 channel											
	I <sup>2</sup> C bus	—	1 channel		1 channel		1 channel		1 channel		1 channel	
Multiplier and divider/multiply-accumulator	• 16 bits × 16 bits = 32 bits (Unsigned or signed) • 32 bits ÷ 32 bits = 32 bits (Unsigned) • 16 bits × 16 bits + 32 bits = 32 bits (Unsigned or signed)											
DMA controller	2 channels											
Vectored interrupt sources	Internal	23	24		24		27		27		27	
	External	3	5		5		6		6		6	
Key interrupt	—											
Reset	• Reset by $\overline{\text{RESET}}$ pin • Internal reset by watchdog timer • Internal reset by power-on-reset • Internal reset by voltage detector • Internal reset by illegal instruction execution <sup>Note</sup> • Internal reset by RAM parity error • Internal reset by illegal-memory access											
Power-on-reset circuit	• Power-on-reset: 1.51 V (TYP.) • Power-down-reset: 1.50 V (TYP.)											
Voltage detector	• Rising edge : 1.67 V to 4.06 V (14 stages) • Falling edge : 1.63 V to 3.98 V (14 stages)											
On-chip debug function	Provided											
Power supply voltage	V <sub>DD</sub> = 1.6 to 5.5 V (T <sub>A</sub> = -40 to +85°C) V <sub>DD</sub> = 2.4 to 5.5 V (T <sub>A</sub> = -40 to +105°C)											
Operating ambient temperature	T <sub>A</sub> = 40 to +85°C (A: Consumer applications, D: Industrial applications ) T <sub>A</sub> = 40 to +105°C (G: Industrial applications)											

**Note** The illegal instruction is generated when instruction code FFH is executed.

Reset by the illegal instruction execution not issued by emulation with the in-circuit emulator or on-chip debug emulator.

- Notes**
1. Total current flowing into V<sub>DD</sub> and EV<sub>DD0</sub>, including the input leakage current flowing when the level of the input pin is fixed to V<sub>DD</sub>, EV<sub>DD0</sub> or V<sub>SS</sub>, EV<sub>SS0</sub>. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
  2. During HALT instruction execution by flash memory.
  3. When high-speed on-chip oscillator and subsystem clock are stopped.
  4. When high-speed system clock and subsystem clock are stopped.
  5. When high-speed on-chip oscillator and high-speed system clock are stopped. When RTCLPC = 1 and setting ultra-low current consumption (AMPHS1 = 1). The current flowing into the RTC is included. However, not including the current flowing into the 12-bit interval timer and watchdog timer.
  6. Not including the current flowing into the RTC, 12-bit interval timer, and watchdog timer.
  7. Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.
    - HS (high-speed main) mode:  $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$  @ 1 MHz to 32 MHz
    - $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$  @ 1 MHz to 16 MHz
    - LS (low-speed main) mode:  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$  @ 1 MHz to 8 MHz
    - LV (low-voltage main) mode:  $1.6\text{ V} \leq V_{DD} \leq 5.5\text{ V}$  @ 1 MHz to 4 MHz
  8. Regarding the value for current to operate the subsystem clock in STOP mode, refer to that in HALT mode.

- Remarks**
1. f<sub>MX</sub>: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
  2. f<sub>IH</sub>: High-speed on-chip oscillator clock frequency
  3. f<sub>SUB</sub>: Subsystem clock frequency (XT1 clock oscillation frequency)
  4. Except subsystem clock operation and STOP mode, temperature condition of the TYP. value is T<sub>A</sub> = 25°C

6. Current flowing only to the A/D converter. The supply current of the RL78 microcontrollers is the sum of  $I_{DD1}$  or  $I_{DD2}$  and  $I_{ADC}$  when the A/D converter operates in an operation mode or the HALT mode.
7. Current flowing only to the LVD circuit. The supply current of the RL78 microcontrollers is the sum of  $I_{DD1}$ ,  $I_{DD2}$  or  $I_{DD3}$  and  $I_{LVD}$  when the LVD circuit is in operation.
8. Current flowing only during data flash rewrite.
9. Current flowing only during self programming.
10. For shift time to the SNOOZE mode, see **18.3.3 SNOOZE mode**.

- Remarks**
1.  $f_{IL}$ : Low-speed on-chip oscillator clock frequency
  2.  $f_{SUB}$ : Subsystem clock frequency (XT1 clock oscillation frequency)
  3.  $f_{CLK}$ : CPU/peripheral hardware clock frequency
  4. Temperature condition of the TYP. value is  $T_A = 25^{\circ}\text{C}$



**(9) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (slave mode, SCKp... external clock input)****(T<sub>A</sub> = -40 to +85°C, 1.8 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V) (1/2)**

Parameter	Symbol	Conditions		HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
				MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
SCKp cycle time <sup>Note 1</sup>	t <sub>KCY2</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V	24 MHz < f <sub>MCK</sub>	14/ f <sub>MCK</sub>		—		—		ns
			20 MHz < f <sub>MCK</sub> ≤ 24 MHz	12/ f <sub>MCK</sub>		—		—		ns
			8 MHz < f <sub>MCK</sub> ≤ 20 MHz	10/ f <sub>MCK</sub>		—		—		ns
			4 MHz < f <sub>MCK</sub> ≤ 8 MHz	8/f <sub>MCK</sub>		16/ f <sub>MCK</sub>		—		ns
			f <sub>MCK</sub> ≤ 4 MHz	6/f <sub>MCK</sub>		10/ f <sub>MCK</sub>		10/ f <sub>MCK</sub>		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V	24 MHz < f <sub>MCK</sub>	20/ f <sub>MCK</sub>		—		—		ns
			20 MHz < f <sub>MCK</sub> ≤ 24 MHz	16/ f <sub>MCK</sub>		—		—		ns
			16 MHz < f <sub>MCK</sub> ≤ 20 MHz	14/ f <sub>MCK</sub>		—		—		ns
			8 MHz < f <sub>MCK</sub> ≤ 16 MHz	12/ f <sub>MCK</sub>		—		—		ns
			4 MHz < f <sub>MCK</sub> ≤ 8 MHz	8/f <sub>MCK</sub>		16/ f <sub>MCK</sub>		—		ns
			f <sub>MCK</sub> ≤ 4 MHz	6/f <sub>MCK</sub>		10/ f <sub>MCK</sub>		10/ f <sub>MCK</sub>		ns
		1.8 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V <sup>Note 2</sup>	24 MHz < f <sub>MCK</sub>	48/ f <sub>MCK</sub>		—		—		ns
			20 MHz < f <sub>MCK</sub> ≤ 24 MHz	36/ f <sub>MCK</sub>		—		—		ns
			16 MHz < f <sub>MCK</sub> ≤ 20 MHz	32/ f <sub>MCK</sub>		—		—		ns
			8 MHz < f <sub>MCK</sub> ≤ 16 MHz	26/ f <sub>MCK</sub>		—		—		ns
			4 MHz < f <sub>MCK</sub> ≤ 8 MHz	16/ f <sub>MCK</sub>		16/ f <sub>MCK</sub>		—		ns
			f <sub>MCK</sub> ≤ 4 MHz	10/ f <sub>MCK</sub>		10/ f <sub>MCK</sub>		10/ f <sub>MCK</sub>		ns

(Notes and Caution are listed on the next page, and Remarks are listed on the page after the next page.)

(2) When reference voltage (+) = AV<sub>REFP</sub>/ANI0 (ADREFP1 = 0, ADREFP0 = 1), reference voltage (-) = AV<sub>REFM</sub>/ANI1 (ADREFM = 1), target pin : ANI16 to ANI26

(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, 1.6 V ≤ AV<sub>REFP</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V, Reference voltage (+) = AV<sub>REFP</sub>, Reference voltage (-) = AV<sub>REFM</sub> = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Resolution	RES		8		10	bit
Overall error <sup>Note 1</sup>	AINL	10-bit resolution EV <sub>DD0</sub> = AV <sub>REFP</sub> = V <sub>DD</sub> <sup>Notes 3, 4</sup>	1.8 V ≤ AV <sub>REFP</sub> ≤ 5.5 V		±5.0	LSB
			1.6 V ≤ AV <sub>REFP</sub> ≤ 5.5 V <sup>Note 5</sup>	1.2	±8.5	LSB
Conversion time	t <sub>CONV</sub>	10-bit resolution Target ANI pin : ANI16 to ANI26	3.6 V ≤ V <sub>DD</sub> ≤ 5.5 V	2.125	39	μs
			2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	3.1875	39	μs
			1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V	17	39	μs
			1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V	57	95	μs
Zero-scale error <sup>Notes 1, 2</sup>	E <sub>ZS</sub>	10-bit resolution EV <sub>DD0</sub> = AV <sub>REFP</sub> = V <sub>DD</sub> <sup>Notes 3, 4</sup>	1.8 V ≤ AV <sub>REFP</sub> ≤ 5.5 V		±0.35	%FSR
			1.6 V ≤ AV <sub>REFP</sub> ≤ 5.5 V <sup>Note 5</sup>		±0.60	%FSR
Full-scale error <sup>Notes 1, 2</sup>	E <sub>FS</sub>	10-bit resolution EV <sub>DD0</sub> = AV <sub>REFP</sub> = V <sub>DD</sub> <sup>Notes 3, 4</sup>	1.8 V ≤ AV <sub>REFP</sub> ≤ 5.5 V		±0.35	%FSR
			1.6 V ≤ AV <sub>REFP</sub> ≤ 5.5 V <sup>Note 5</sup>		±0.60	%FSR
Integral linearity error <sup>Note 1</sup>	ILE	10-bit resolution EV <sub>DD0</sub> = AV <sub>REFP</sub> = V <sub>DD</sub> <sup>Notes 3, 4</sup>	1.8 V ≤ AV <sub>REFP</sub> ≤ 5.5 V		±3.5	LSB
			1.6 V ≤ AV <sub>REFP</sub> ≤ 5.5 V <sup>Note 5</sup>		±6.0	LSB
Differential linearity error <sup>Note 1</sup>	DLE	10-bit resolution EV <sub>DD0</sub> = AV <sub>REFP</sub> = V <sub>DD</sub> <sup>Notes 3, 4</sup>	1.8 V ≤ AV <sub>REFP</sub> ≤ 5.5 V		±2.0	LSB
			1.6 V ≤ AV <sub>REFP</sub> ≤ 5.5 V <sup>Note 5</sup>		±2.5	LSB
Analog input voltage	V <sub>AIN</sub>	ANI16 to ANI26	0		AV <sub>REFP</sub> and EV <sub>DD0</sub>	V

**Notes** 1. Excludes quantization error (±1/2 LSB).

2. This value is indicated as a ratio (%FSR) to the full-scale value.

3. When AV<sub>REFP</sub> < V<sub>DD</sub>, the MAX. values are as follows.

Overall error: Add ±1.0 LSB to the MAX. value when AV<sub>REFP</sub> = V<sub>DD</sub>.

Zero-scale error/Full-scale error: Add ±0.05%FSR to the MAX. value when AV<sub>REFP</sub> = V<sub>DD</sub>.

Integral linearity error/ Differential linearity error: Add ±0.5 LSB to the MAX. value when AV<sub>REFP</sub> = V<sub>DD</sub>.

4. When AV<sub>REFP</sub> < EV<sub>DD0</sub> ≤ V<sub>DD</sub>, the MAX. values are as follows.

Overall error: Add ±4.0 LSB to the MAX. value when AV<sub>REFP</sub> = V<sub>DD</sub>.

Zero-scale error/Full-scale error: Add ±0.20%FSR to the MAX. value when AV<sub>REFP</sub> = V<sub>DD</sub>.

Integral linearity error/ Differential linearity error: Add ±2.0 LSB to the MAX. value when AV<sub>REFP</sub> = V<sub>DD</sub>.

5. When the conversion time is set to 57 μs (min.) and 95 μs (max.).

## 3.3 DC Characteristics

## 3.3.1 Pin characteristics

(T<sub>A</sub> =  $-40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq \text{EV}_{\text{DD}0} = \text{EV}_{\text{DD}1} \leq \text{V}_{\text{DD}} \leq 5.5\text{ V}$ ,  $\text{V}_{\text{SS}} = \text{EV}_{\text{SS}0} = \text{EV}_{\text{SS}1} = 0\text{ V}$ ) (1/5)

Items	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output current, high <sup>Note 1</sup>	I <sub>OH1</sub>	Per pin for P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P130, P140 to P147	$2.4\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$		-3.0 <sup>Note 2</sup>	mA
		Total of P00 to P04, P07, P32 to P37, P40 to P47, P102 to P106, P120, P125 to P127, P130, P140 to P145 (When duty $\leq 70\%$ <sup>Note 3</sup> )	$4.0\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$		-30.0	mA
			$2.7\text{ V} \leq \text{EV}_{\text{DD}0} < 4.0\text{ V}$		-10.0	mA
			$2.4\text{ V} \leq \text{EV}_{\text{DD}0} < 2.7\text{ V}$		-5.0	mA
		Total of P05, P06, P10 to P17, P30, P31, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100, P101, P110 to P117, P146, P147 (When duty $\leq 70\%$ <sup>Note 3</sup> )	$4.0\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$		-30.0	mA
			$2.7\text{ V} \leq \text{EV}_{\text{DD}0} < 4.0\text{ V}$		-19.0	mA
			$2.4\text{ V} \leq \text{EV}_{\text{DD}0} < 2.7\text{ V}$		-10.0	mA
		Total of all pins (When duty $\leq 70\%$ <sup>Note 3</sup> )	$2.4\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$		-60.0	mA
	I <sub>OH2</sub>	Per pin for P20 to P27, P150 to P156	$2.4\text{ V} \leq \text{V}_{\text{DD}} \leq 5.5\text{ V}$		-0.1 <sup>Note 2</sup>	mA
		Total of all pins (When duty $\leq 70\%$ <sup>Note 3</sup> )	$2.4\text{ V} \leq \text{V}_{\text{DD}} \leq 5.5\text{ V}$		-1.5	mA

**Notes** 1. Value of current at which the device operation is guaranteed even if the current flows from the EV<sub>DD0</sub>, EV<sub>DD1</sub>, V<sub>DD</sub> pins to an output pin.

2. Do not exceed the total current value.

3. Specification under conditions where the duty factor  $\leq 70\%$ .

The output current value that has changed to the duty factor  $> 70\%$  the duty ratio can be calculated with the following expression (when changing the duty factor from 70% to n%).

- Total output current of pins =  $(I_{\text{OH}} \times 0.7)/(n \times 0.01)$

<Example> Where  $n = 80\%$  and  $I_{\text{OH}} = -10.0\text{ mA}$

$$\text{Total output current of pins} = (-10.0 \times 0.7)/(80 \times 0.01) \cong -8.7\text{ mA}$$

However, the current that is allowed to flow into one pin does not vary depending on the duty factor.

A current higher than the absolute maximum rating must not flow into one pin.

**Caution** P00, P02 to P04, P10 to P15, P17, P43 to P45, P50, P52 to P55, P71, P74, P80 to P82, P96, and P142 to P144 do not output high level in N-ch open-drain mode.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

- Notes**
1. Total current flowing into  $V_{DD}$  and  $EV_{DD0}$ , including the input leakage current flowing when the level of the input pin is fixed to  $V_{DD}$ ,  $EV_{DD0}$  or  $V_{SS}$ ,  $EV_{SS0}$ . The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
  2. During HALT instruction execution by flash memory.
  3. When high-speed on-chip oscillator and subsystem clock are stopped.
  4. When high-speed system clock and subsystem clock are stopped.
  5. When high-speed on-chip oscillator and high-speed system clock are stopped. When  $RTCLPC = 1$  and setting ultra-low current consumption ( $AMPHS1 = 1$ ). The current flowing into the RTC is included. However, not including the current flowing into the 12-bit interval timer and watchdog timer.
  6. Not including the current flowing into the RTC, 12-bit interval timer, and watchdog timer.
  7. Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.  
 HS (high-speed main) mode:  $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }32\text{ MHz}$   
 $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }16\text{ MHz}$
  8. Regarding the value for current operate the subsystem clock in STOP mode, refer to that in HALT mode.

- Remarks**
1.  $f_{MX}$ : High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
  2.  $f_{IH}$ : High-speed on-chip oscillator clock frequency
  3.  $f_{SUB}$ : Subsystem clock frequency (XT1 clock oscillation frequency)
  4. Except subsystem clock operation and STOP mode, temperature condition of the TYP. value is  $T_A = 25^{\circ}\text{C}$

## (2) Flash ROM: 96 to 256 KB of 30- to 100-pin products

(TA =  $-40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq \text{EV}_{\text{DD}0} = \text{EV}_{\text{DD}1} \leq \text{V}_{\text{DD}} \leq 5.5\text{ V}$ ,  $\text{V}_{\text{SS}} = \text{EV}_{\text{SS}0} = \text{EV}_{\text{SS}1} = 0\text{ V}$ ) (1/2)

Parameter	Symbol	Conditions					MIN.	TYP.	MAX.	Unit
Supply current Note 1	I <sub>DD1</sub>	Operating mode	HS (high-speed main) mode Note 5	$f_{\text{IH}} = 32\text{ MHz}$ Note 3	Basic operation	$\text{V}_{\text{DD}} = 5.0\text{ V}$		2.3		mA
						$\text{V}_{\text{DD}} = 3.0\text{ V}$		2.3		mA
					Normal operation	$\text{V}_{\text{DD}} = 5.0\text{ V}$		5.2	9.2	mA
						$\text{V}_{\text{DD}} = 3.0\text{ V}$		5.2	9.2	mA
				$f_{\text{IH}} = 24\text{ MHz}$ Note 3	Normal operation	$\text{V}_{\text{DD}} = 5.0\text{ V}$		4.1	7.0	mA
						$\text{V}_{\text{DD}} = 3.0\text{ V}$		4.1	7.0	mA
				$f_{\text{IH}} = 16\text{ MHz}$ Note 3	Normal operation	$\text{V}_{\text{DD}} = 5.0\text{ V}$		3.0	5.0	mA
						$\text{V}_{\text{DD}} = 3.0\text{ V}$		3.0	5.0	mA
			HS (high-speed main) mode Note 5	$f_{\text{MX}} = 20\text{ MHz}$ Note 2, $\text{V}_{\text{DD}} = 5.0\text{ V}$	Normal operation	Square wave input		3.4	5.9	mA
						Resonator connection		3.6	6.0	mA
				$f_{\text{MX}} = 20\text{ MHz}$ Note 2, $\text{V}_{\text{DD}} = 3.0\text{ V}$	Normal operation	Square wave input		3.4	5.9	mA
						Resonator connection		3.6	6.0	mA
				$f_{\text{MX}} = 10\text{ MHz}$ Note 2, $\text{V}_{\text{DD}} = 5.0\text{ V}$	Normal operation	Square wave input		2.1	3.5	mA
						Resonator connection		2.1	3.5	mA
				$f_{\text{MX}} = 10\text{ MHz}$ Note 2, $\text{V}_{\text{DD}} = 3.0\text{ V}$	Normal operation	Square wave input		2.1	3.5	mA
						Resonator connection		2.1	3.5	mA
		Subsystem clock operation		$f_{\text{SUB}} = 32.768\text{ kHz}$ Note 4 $T_A = -40^\circ\text{C}$	Normal operation	Square wave input		4.8	5.9	$\mu\text{A}$
						Resonator connection		4.9	6.0	$\mu\text{A}$
				$f_{\text{SUB}} = 32.768\text{ kHz}$ Note 4 $T_A = +25^\circ\text{C}$	Normal operation	Square wave input		4.9	5.9	$\mu\text{A}$
						Resonator connection		5.0	6.0	$\mu\text{A}$
				$f_{\text{SUB}} = 32.768\text{ kHz}$ Note 4 $T_A = +50^\circ\text{C}$	Normal operation	Square wave input		5.0	7.6	$\mu\text{A}$
						Resonator connection		5.1	7.7	$\mu\text{A}$
				$f_{\text{SUB}} = 32.768\text{ kHz}$ Note 4 $T_A = +70^\circ\text{C}$	Normal operation	Square wave input		5.2	9.3	$\mu\text{A}$
						Resonator connection		5.3	9.4	$\mu\text{A}$
				$f_{\text{SUB}} = 32.768\text{ kHz}$ Note 4 $T_A = +85^\circ\text{C}$	Normal operation	Square wave input		5.7	13.3	$\mu\text{A}$
						Resonator connection		5.8	13.4	$\mu\text{A}$
				$f_{\text{SUB}} = 32.768\text{ kHz}$ Note 4 $T_A = +105^\circ\text{C}$	Normal operation	Square wave input		10.0	46.0	$\mu\text{A}$
						Resonator connection		10.0	46.0	$\mu\text{A}$

(Notes and Remarks are listed on the next page.)

5. The smaller maximum transfer rate derived by using  $f_{MCK}/12$  or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when  $2.4\text{ V} \leq EV_{DD0} < 3.3\text{ V}$  and  $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{1.5}{V_b})\} \times 3} \text{ [bps]}$$

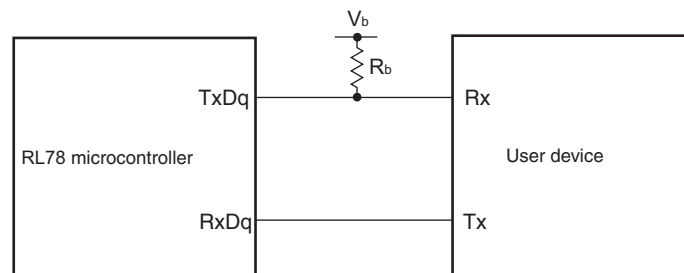
$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{1.5}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [%]}$$

\* This value is the theoretical value of the relative difference between the transmission and reception sides.

6. This value as an example is calculated when the conditions described in the “Conditions” column are met. Refer to Note 5 above to calculate the maximum transfer rate under conditions of the customer.

**Caution** Select the TTL input buffer for the RxDq pin and the N-ch open drain output ( $V_{DD}$  tolerance (for the 20- to 52-pin products)/ $EV_{DD}$  tolerance (for the 64- to 100-pin products)) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg). For  $V_{IH}$  and  $V_{IL}$ , see the DC characteristics with TTL input buffer selected.

UART mode connection diagram (during communication at different potential)



**(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output) (3/3)****( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq EV_{DD0} = EV_{DD1} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = EV_{SS0} = EV_{SS1} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		Unit
			MIN.	MAX.	
Slp setup time (to SCKp↓) <sup>Note</sup>	$t_{SIK1}$	$4.0\text{ V} \leq EV_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$	88		ns
		$2.7\text{ V} \leq EV_{DD0} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	88		ns
		$2.4\text{ V} \leq EV_{DD0} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	220		ns
Slp hold time (from SCKp↓) <sup>Note</sup>	$t_{KSI1}$	$4.0\text{ V} \leq EV_{DD0} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$	38		ns
		$2.7\text{ V} \leq EV_{DD0} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	38		ns
		$2.4\text{ V} \leq EV_{DD0} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	38		ns
Delay time from SCKp↑ to SOp output <sup>Note</sup>	$t_{KSO1}$	$4.0\text{ V} \leq EV_{DD0} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$		50	ns
		$2.7\text{ V} \leq EV_{DD0} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$		50	ns
		$2.4\text{ V} \leq EV_{DD0} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$		50	ns

**Note** When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

**Caution** Select the TTL input buffer for the Slp pin and the N-ch open drain output ( $V_{DD}$  tolerance (for the 20- to 52-pin products)/ $EV_{DD}$  tolerance (for the 64- to 100-pin products)) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For  $V_{IH}$  and  $V_{IL}$ , see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the next page.)

**(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I<sup>2</sup>C mode) (1/2)****( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq EV_{DD0} = EV_{DD1} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = EV_{SS0} = EV_{SS1} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		Unit
			MIN.	MAX.	
SCLr clock frequency	$f_{SCL}$	$4.0\text{ V} \leq EV_{DD0} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 50\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$		400 <sup>Note 1</sup>	kHz
		$2.7\text{ V} \leq EV_{DD0} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 50\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$		400 <sup>Note 1</sup>	kHz
		$4.0\text{ V} \leq EV_{DD0} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.8\text{ k}\Omega$		100 <sup>Note 1</sup>	kHz
		$2.7\text{ V} \leq EV_{DD0} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$		100 <sup>Note 1</sup>	kHz
		$2.4\text{ V} \leq EV_{DD0} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$		100 <sup>Note 1</sup>	kHz
Hold time when SCLr = "L"	$t_{LOW}$	$4.0\text{ V} \leq EV_{DD0} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 50\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	1200		ns
		$2.7\text{ V} \leq EV_{DD0} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 50\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	1200		ns
		$4.0\text{ V} \leq EV_{DD0} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.8\text{ k}\Omega$	4600		ns
		$2.7\text{ V} \leq EV_{DD0} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	4600		ns
		$2.4\text{ V} \leq EV_{DD0} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	4650		ns
Hold time when SCLr = "H"	$t_{HIGH}$	$4.0\text{ V} \leq EV_{DD0} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 50\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	620		ns
		$2.7\text{ V} \leq EV_{DD0} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 50\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	500		ns
		$4.0\text{ V} \leq EV_{DD0} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.8\text{ k}\Omega$	2700		ns
		$2.7\text{ V} \leq EV_{DD0} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	2400		ns
		$2.4\text{ V} \leq EV_{DD0} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	1830		ns

(Notes and Caution are listed on the next page, and Remarks are listed on the page after the next page.)



**(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I<sup>2</sup>C mode) (2/2)****( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq \text{EV}_{\text{DD}0} = \text{EV}_{\text{DD}1} \leq \text{V}_{\text{DD}} \leq 5.5\text{ V}$ ,  $\text{V}_{\text{SS}} = \text{EV}_{\text{SS}0} = \text{EV}_{\text{SS}1} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		Unit
			MIN.	MAX.	
Data setup time (reception)	$t_{\text{SU:DAT}}$	$4.0\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq \text{V}_b \leq 4.0\text{ V}$ , $C_b = 50\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	$1/f_{\text{MCK}} + 340$ Note 2		ns
		$2.7\text{ V} \leq \text{EV}_{\text{DD}0} < 4.0\text{ V}$ , $2.3\text{ V} \leq \text{V}_b \leq 2.7\text{ V}$ , $C_b = 50\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	$1/f_{\text{MCK}} + 340$ Note 2		ns
		$4.0\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq \text{V}_b \leq 4.0\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.8\text{ k}\Omega$	$1/f_{\text{MCK}} + 760$ Note 2		ns
		$2.7\text{ V} \leq \text{EV}_{\text{DD}0} < 4.0\text{ V}$ , $2.3\text{ V} \leq \text{V}_b \leq 2.7\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	$1/f_{\text{MCK}} + 760$ Note 2		ns
		$2.4\text{ V} \leq \text{EV}_{\text{DD}0} < 3.3\text{ V}$ , $1.6\text{ V} \leq \text{V}_b \leq 2.0\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	$1/f_{\text{MCK}} + 570$ Note 2		ns
Data hold time (transmission)	$t_{\text{HD:DAT}}$	$4.0\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq \text{V}_b \leq 4.0\text{ V}$ , $C_b = 50\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	0	770	ns
		$2.7\text{ V} \leq \text{EV}_{\text{DD}0} < 4.0\text{ V}$ , $2.3\text{ V} \leq \text{V}_b \leq 2.7\text{ V}$ , $C_b = 50\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	0	770	ns
		$4.0\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq \text{V}_b \leq 4.0\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.8\text{ k}\Omega$	0	1420	ns
		$2.7\text{ V} \leq \text{EV}_{\text{DD}0} < 4.0\text{ V}$ , $2.3\text{ V} \leq \text{V}_b \leq 2.7\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	0	1420	ns
		$2.4\text{ V} \leq \text{EV}_{\text{DD}0} < 3.3\text{ V}$ , $1.6\text{ V} \leq \text{V}_b \leq 2.0\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	0	1215	ns

**Notes** 1. The value must also be equal to or less than  $f_{\text{MCK}}/4$ .2. Set the  $f_{\text{MCK}}$  value to keep the hold time of  $\text{SCLr} = \text{"L"}$  and  $\text{SCLr} = \text{"H"}$ .

**Caution** Select the TTL input buffer and the N-ch open drain output ( $\text{V}_{\text{DD}}$  tolerance (for the 20- to 52-pin products)/ $\text{EV}_{\text{DD}}$  tolerance (for the 64- to 100-pin products)) mode for the  $\text{SDAr}$  pin and the N-ch open drain output ( $\text{V}_{\text{DD}}$  tolerance (for the 20- to 52-pin products)/ $\text{EV}_{\text{DD}}$  tolerance (for the 64- to 100-pin products)) mode for the  $\text{SCLr}$  pin by using port input mode register g (PIMg) and port output mode register g (POMg). For  $\text{V}_{\text{IH}}$  and  $\text{V}_{\text{IL}}$ , see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the next page.)

- (4) When reference voltage (+) = Internal reference voltage (ADREFP1 = 1, ADREFP0 = 0), reference voltage (–) =  $AV_{REFM}/ANI1$  (ADREFM = 1), target pin : ANI0, ANI2 to ANI14, ANI16 to ANI26

( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq EV_{DD0} = EV_{DD1} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = EV_{SS0} = EV_{SS1} = 0\text{ V}$ , Reference voltage (+) =  $V_{BGR}$ <sup>Note 3</sup>, Reference voltage (–) =  $AV_{REFM}$ <sup>Note 4</sup> = 0 V, HS (high-speed main) mode)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Resolution	RES			8			bit
Conversion time	$t_{CONV}$	8-bit resolution	$2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	17		39	$\mu\text{s}$
Zero-scale error <sup>Notes 1, 2</sup>	E <sub>ZS</sub>	8-bit resolution	$2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$			$\pm 0.60$	%FSR
Integral linearity error <sup>Note 1</sup>	ILE	8-bit resolution	$2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$			$\pm 2.0$	LSB
Differential linearity error <sup>Note 1</sup>	DLE	8-bit resolution	$2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$			$\pm 1.0$	LSB
Analog input voltage	$V_{AIN}$			0		$V_{BGR}$ <sup>Note 3</sup>	V

**Notes** 1. Excludes quantization error ( $\pm 1/2$  LSB).

2. This value is indicated as a ratio (%FSR) to the full-scale value.

3. Refer to **3.6.2 Temperature sensor/internal reference voltage characteristics**.

4. When reference voltage (–) =  $V_{SS}$ , the MAX. values are as follows.

Zero-scale error: Add  $\pm 0.35\%$ FSR to the MAX. value when reference voltage (–) =  $AV_{REFM}$ .

Integral linearity error: Add  $\pm 0.5$  LSB to the MAX. value when reference voltage (–) =  $AV_{REFM}$ .

Differential linearity error: Add  $\pm 0.2$  LSB to the MAX. value when reference voltage (–) =  $AV_{REFM}$ .

### 3.6.2 Temperature sensor/internal reference voltage characteristics

( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ , HS (high-speed main) mode)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Temperature sensor output voltage	$V_{TMPS25}$	Setting ADS register = 80H, $T_A = +25^\circ\text{C}$		1.05		V
Internal reference voltage	$V_{BGR}$	Setting ADS register = 81H	1.38	1.45	1.5	V
Temperature coefficient	$F_{VTMPS}$	Temperature sensor that depends on the temperature		–3.6		mV/ $^\circ\text{C}$
Operation stabilization wait time	$t_{AMP}$		5			$\mu\text{s}$

## 3.6.5 Power supply voltage rising slope characteristics

 $(T_A = -40$  to  $+105^\circ\text{C}$ ,  $V_{SS} = 0$  V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Power supply voltage rising slope	$S_{VDD}$				54	V/ms

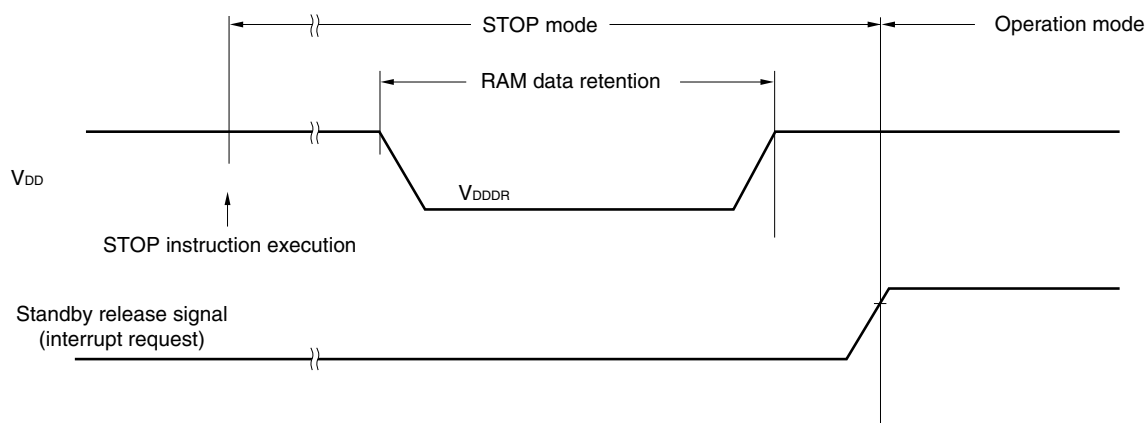
**Caution** Make sure to keep the internal reset state by the LVD circuit or an external reset until  $V_{DD}$  reaches the operating voltage range shown in 3.4 AC Characteristics.

## 3.7 RAM Data Retention Characteristics

 $(T_A = -40$  to  $+105^\circ\text{C}$ ,  $V_{SS} = 0$  V)

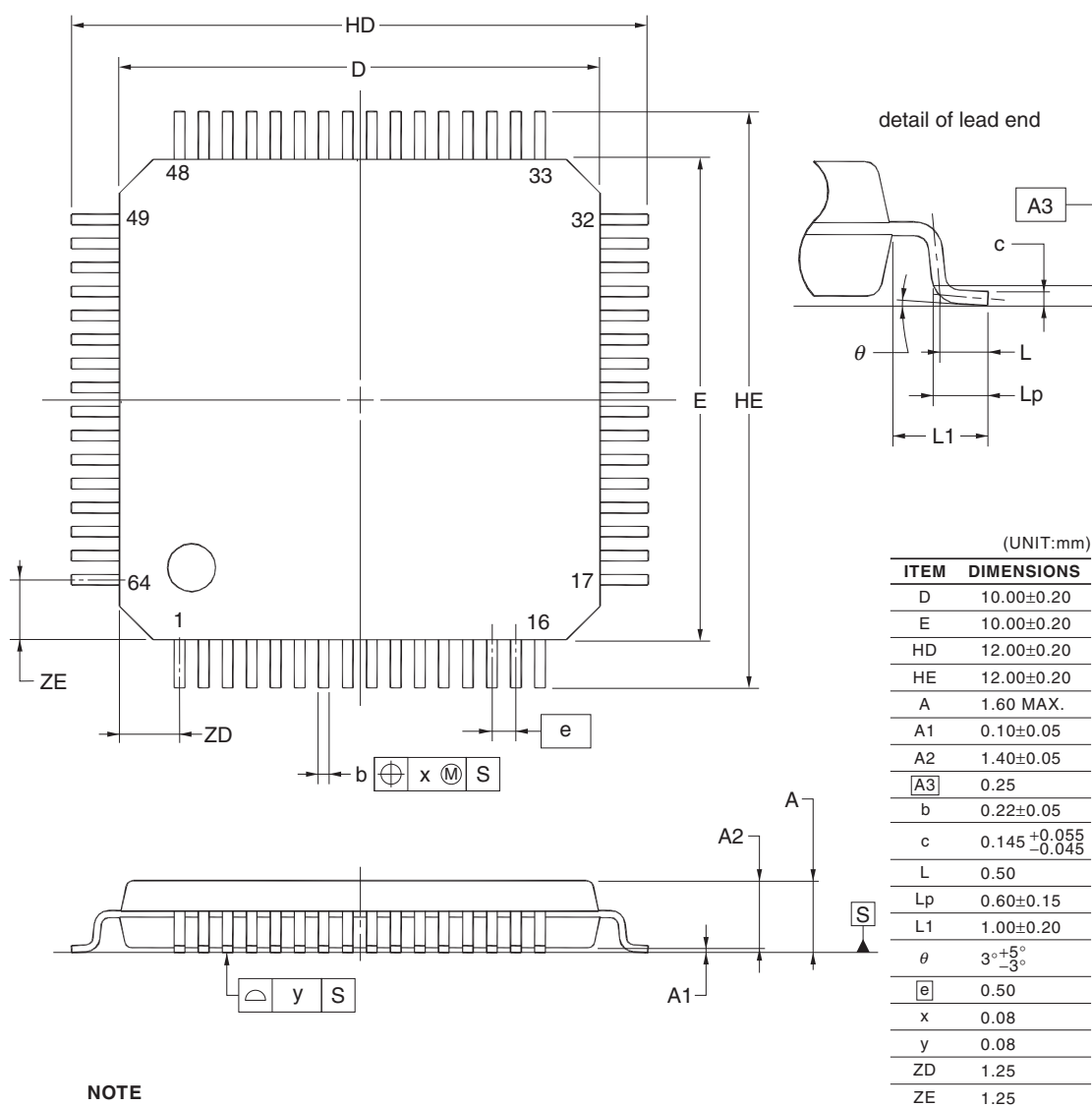
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Data retention supply voltage	$V_{DDDR}$		1.44 <sup>Note</sup>		5.5	V

**Note** This depends on the POR detection voltage. For a falling voltage, data in RAM are retained until the voltage reaches the level that triggers a POR reset but not once it reaches the level at which a POR reset is generated.



R5F100LCAFB, R5F100LDAFB, R5F100LEAFB, R5F100LFAFB, R5F100LGAFB, R5F100LHAFB, R5F100LJAFB,  
 R5F100LKAFB, R5F100LLAFB  
 R5F101LCAFB, R5F101LDAFB, R5F101LEAFB, R5F101LFAFB, R5F101LGAFB, R5F101LHAFB,  
 R5F101LJAFB, R5F101LKAFB, R5F101LLAFB  
 R5F100LCDFB, R5F100LDDFB, R5F100LEDFB, R5F100LDFB, R5F100LGDFB, R5F100LHDFB, R5F100LJDFB,  
 R5F100LKDFB, R5F100LLDFB  
 R5F101LCDFB, R5F101LDDFB, R5F101LEDFB, R5F101LDFB, R5F101LGDFB, R5F101LHDFB,  
 R5F101LJDFB, R5F101LKDFB, R5F101LLDFB  
 R5F100LCGFB, R5F100LDGFB, R5F100LEGFB, R5F100LFGFB, R5F100LGGFB, R5F100LHGF, R5F100LJGF

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-LFQFP64-10x10-0.50	PLQP0064KF-A	P64GB-50-UEU-2	0.35



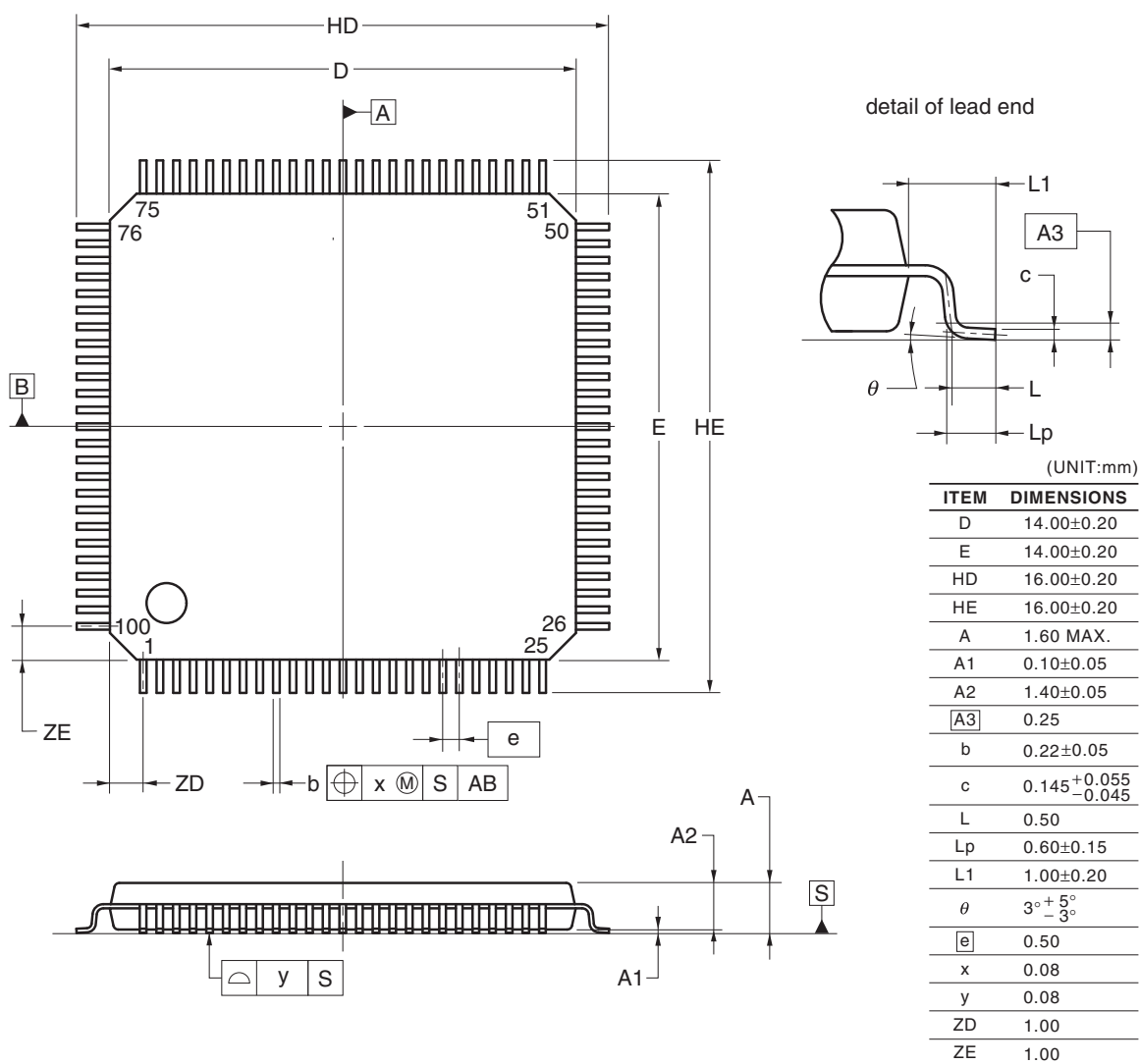
#### NOTE

Each lead centerline is located within 0.08 mm of its true position at maximum material condition.

### 4.13 100-pin Products

R5F100PFAFB, R5F100PGA FB, R5F100PHA FB, R5F100PJA FB, R5F100PKA FB, R5F100PLA FB  
R5F101PFA FB, R5F101PGA FB, R5F101PHA FB, R5F101PJA FB, R5F101PKA FB, R5F101PLA FB  
R5F100PFD FB, R5F100PGD FB, R5F100PHD FB, R5F100PJD FB, R5F100PKD FB, R5F100PLD FB  
R5F101PFD FB, R5F101PGD FB, R5F101PHD FB, R5F101PJD FB, R5F101PKD FB, R5F101PLD FB  
R5F100PFG FB, R5F100PGG FB, R5F100PHG FB, R5F100PJG FB

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-LFQFP100-14x14-0.50	PLQP0100KE-A	P100GC-50-GBR-1	0.69



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